VS-HFA16PA120C-N3

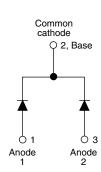
Vishay Semiconductors

HEXFRED[®] Ultrafast Soft Recovery Diode, 2 x 8 A



www.vishay.com

SHAY



PRIMARY CHARACTERISTICS								
I _{F(AV)}	2 x 8 A							
V _R	1200 V							
V _F at I _F	2.4 V							
t _{rr} typ.	28 ns							
T _J max.	150 °C							
Package	TO-247AC 3L							
Circuit configuration	Common cathode							

FEATURES

- · Ultrafast and ultrasoft recovery
- Very low I_{RRM} and Q_{rr}
- Designed and qualified according to JEDEC[®]-JESD 47
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

BENEFITS

- Reduced RFI and EMI
- · Reduced power loss in diode and switching transistor
- Higher frequency operation
- Reduced snubbing
- · Reduced parts count

DESCRIPTION

VS-HFA16PA120C... is a state of the art ultrafast recovery diode. Employing the latest in epitaxial construction and advanced processing techniques it features a superb combination of characteristics which result in performance which is unsurpassed by any rectifier previously available. With basic ratings of 1200 V and 8 A per leg continuous current, the VS-HFA16PA120C... is especially well suited for use as the companion diode for IGBTs and MOSFETs. In addition to ultrafast recovery time, the HEXFRED® product line features extremely low values of peak recovery current (I_{RRM}) and does not exhibit any tendency to "snap-off" during the t_b portion of recovery. The HEXFRED features combine to offer designers a rectifier with lower noise and significantly lower switching losses in both the diode and the switching transistor. These HEXFRED advantages can help to significantly reduce snubbing, component count and heatsink sizes. The HEXFRED VS-HFA16PA120C... is ideally suited for applications in power supplies and power conversion systems (such as inverters), motor drives, and many other similar applications where high speed, high efficiency is needed.

ABSOLUTE MAXIMUM RATINGS										
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS						
Cathode to anode voltage	V _R		1200	V						
Maximum continuous forward currentper leg	I_	T _C = 100 °C	8							
per device	I _F		16	А						
Single pulse forward current	I _{FSM}	t _p = 10 ms	130	~						
Maximum repetitive forward current	I _{FRM}		32							
Maximum power dissipation	р	T _C = 25 °C	73.5	W						
	PD	T _C = 100 °C	29	vv						
Operating junction and storage temperature range	T _J , T _{Stg}		-55 to +150	°C						

Revision: 11-Oct-2019



RoHS COMPLIANT HALOGEN FREE



www.vishay.com

VISHAY

Vishay Semiconductors

ELECTRICAL SPECIFICATIONS PER LEG ($T_J = 25 \text{ °C}$ unless otherwise specified)										
PARAMETER	MIN.	TYP.	MAX.	UNITS						
Cathode to anode breakdown voltage	V _{BR}	I _R = 100 μA	1200	-	-					
Maximum forward voltage		I _F = 8.0 A	-	2.6	3.3	v				
	V _{FM}	I _F = 16 A	3.4	4.3						
		I _F = 8.0 A, T _J = 125 °C	-	2.4	3.1					
Maximum reverse		$V_{R} = V_{R}$ rated	-	0.31	10					
leakage current	I _{RM}	$T_J = 125 \text{ °C}, V_R = 0.8 \text{ x } V_R \text{ rated}$	-	135	1000	μA				
Junction capacitance	CT	V _R = 200 V	-	11	20	pF				
Series inductance	L _S	Measured lead to lead 5 mm from package	-	8.0	-	nH				

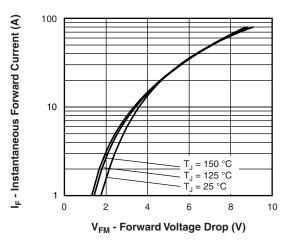
DYNAMIC RECOVERY CHARACTERISTICS PER LEG ($T_J = 25$ °C unless otherwise specified)										
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS			
Reverse recovery time	t _{rr}	$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 200$	-	28	-					
	t _{rr1}	T _J = 25 °C		-	63	95	ns			
	t _{rr2}	T _J = 125 °C		-	106	160				
De els vers es services t	I _{RRM1}	T _J = 25 °C		-	4.5	8.0	- A nC - Α/μs			
Peak recovery current	I _{RRM2}	T _J = 125 °C	I _F = 8.0 A dI _F /dt = 200 A/μs	-	6.2	11				
	Q _{rr1}	T _J = 25 °C	$V_{\rm R} = 200 \text{ V}$	-	140	380				
Reverse recovery charge	Q _{rr2}	T _J = 125 °C		-	335	880				
Peak rate of recovery current during ${\rm t}_{\rm b}$	dl _{(rec)M} /dt1	T _J = 25 °C		-	133	-				
	dl _{(rec)M} /dt2	T _J = 125 °C		-	85	-				

THERMAL - MECHANICAL SPECIFICATIONS										
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS				
Lead temperature	T _{lead}	0.063" from case (1.6 mm) for 10 s	-	-	300	°C				
Thermal resistance, junction to case	R _{thJC}		-	-	1.7					
Thermal resistance, junction to ambient	R _{thJA}	Typical socket mount	-	-	40	K/W				
Thermal resistance, case to heatsink	R _{thCS}	Mounting surface, flat, smooth, and greased	-	0.25	-					
Woight			-	6.0	-	g				
Weight			-	0.21	-	oz.				
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)				
Marking device		Case style TO-247AC 3L	HFA16PA120C							

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



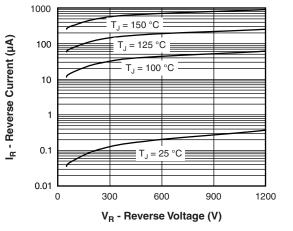
Vishay Semiconductors

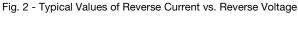


www.vishay.com

SHAY

Fig. 1 - Maximum Forward Voltage Drop Characteristics





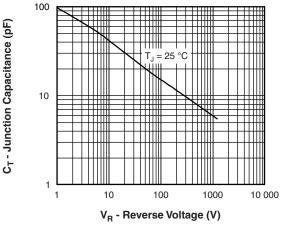
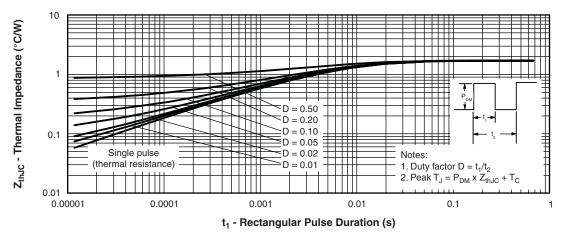
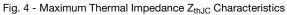


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

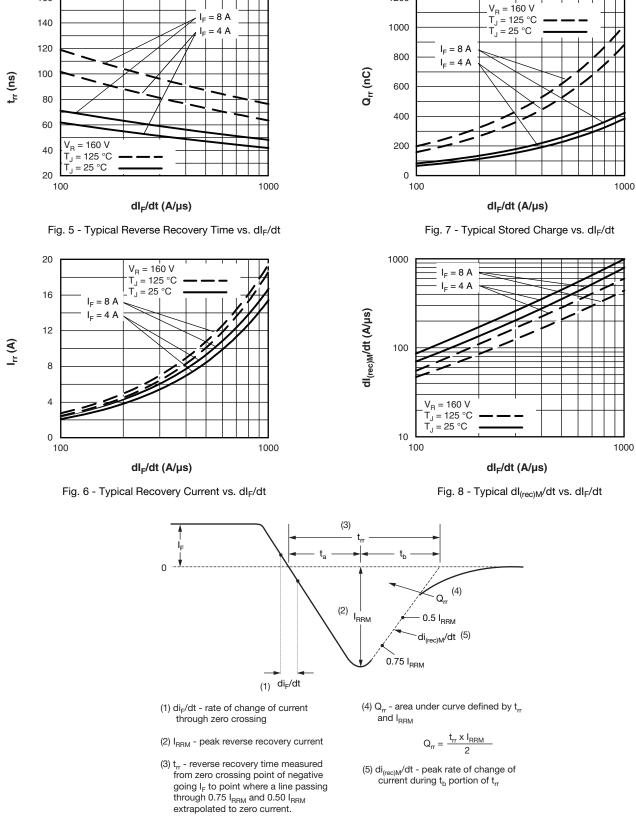




For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



Vishay Semiconductors



1200

Fig. 9 - Reverse Recovery Waveform and Definitions

Revision: 11-Oct-2019 4 Document Number: 94055 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

ISHAY.

160

www.vishay.com

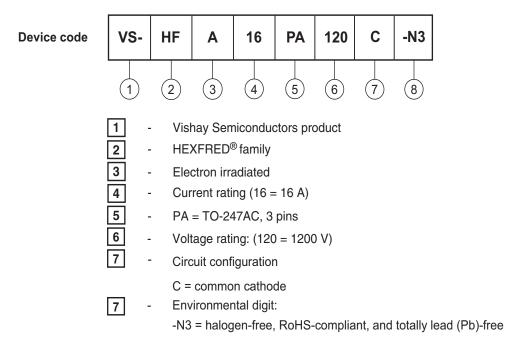


Vishay Semiconductors

www.vishay.com

ORDERING INFORMATION TABLE

/ISHAY



ORDERING INFORMATION (Example)								
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
VS-HFA16PA120C-N3	25	500	Antistatic plastic tube					

LINKS TO RELATED DOCUMENTS							
Dimensions	www.vishay.com/doc?96138						
Part marking information	www.vishay.com/doc?95007						

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>

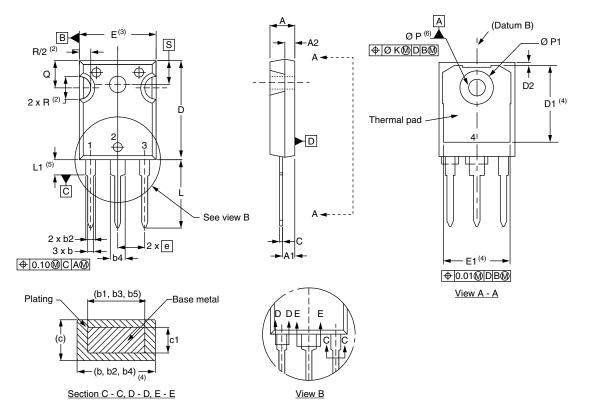


Outline Dimensions

Vishay Semiconductors

TO-247AC 3L

DIMENSIONS in millimeters and inches



SYMBOL	MILLIN	IETERS	INCHES		NOTES	NOTES	SYMBOL	MILLIMETERS		INCHES		NOTES
STIVIBOL	MIN.	MAX.	MIN.	MAX.	NOTES	23	STIVIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.65	5.31	0.183	0.209			D2	0.51	1.35	0.020	0.053	
A1	2.21	2.59	0.087	0.102			E	15.29	15.87	0.602	0.625	3
A2	1.17	1.37	0.046	0.054			E1	13.46	-	0.53	-	
b	0.99	1.40	0.039	0.055			е	5.46	BSC	0.215	5 BSC	
b1	0.99	1.35	0.039	0.053			ØК	0.2	254	0.0	010	
b2	1.65	2.39	0.065	0.094			L	14.20	16.10	0.559	0.634	
b3	1.65	2.34	0.065	0.092			L1	3.71	4.29	0.146	0.169	
b4	2.59	3.43	0.102	0.135			ØΡ	3.56	3.66	0.14	0.144	
b5	2.59	3.38	0.102	0.133			Ø P1	-	7.39	-	0.291	
с	0.38	0.89	0.015	0.035			Q	5.31	5.69	0.209	0.224	
c1	0.38	0.84	0.015	0.033			R	4.52	5.49	0.178	0.216	
D	19.71	20.70	0.776	0.815	3]	S	5.51	BSC	0.217	' BSC	
D1	13.08	-	0.515	-	4]						

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5M-1994

(2) Contour of slot optional

(3) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

⁽⁴⁾ Thermal pad contour optional with dimensions D1 and E1

⁽⁵⁾ Lead finish uncontrolled in L1

(6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-247 with exception of dimension Q

Revision: 20-Jun-17

1



www.vishay.com

Legal Disclaimer Notice

Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

© 2019 VISHAY INTERTECHNOLOGY, INC. ALL RIGHTS RESERVED

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Rectifiers category:

Click to view products by Vishay manufacturer:

Other Similar products are found below :

 70HFR40
 RL252-TP
 150KR30A
 1N5397
 NTE5841
 NTE6038
 SCF5000
 1N4002G
 1N4005-TR
 JANS1N6640US
 VS-80-7161
 481235F

 RRE02VS6SGTR
 067907F
 MS306
 70HF40
 T85HFL60S02
 US2JFL-TP
 A1N5404G-G
 CRS04(T5L,TEMQ)
 ACGRA4007-HF

 ACGRB207-HF
 CLH03(TE16L,Q)
 ACGRC307-HF
 ACEFC304-HF
 NTE6356
 NTE6002
 NTE6002
 NTE6039
 NTE6077

 85HFR60
 40HFR60
 1N1186RA
 70HF120
 85HFR80
 D126A45C
 SCF7500
 D251N08B
 SCHJ22.5K
 SM100
 SCPA2
 SCH10000
 SDHD5K

 VS-12FL100S10
 ACGRA4001-HF
 D1821SH45T PR
 D1251S45T
 NTE5990
 NTE6358